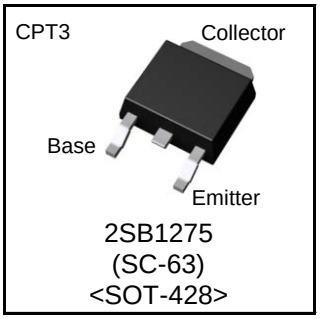
2SB1275

PNP -1.5A -160V Middle Power Transistor

Datasheet

Parameter	Value
V_{CEO}	−160V
I_C	−1.5A

●Outline

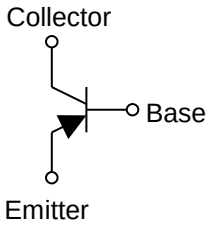


2SB1275
(SC-63)
<SOT-428>

●Features

1) Suitable for Middle Power Driver
2) Complementary NPN Types : 2SD1918
3) High voltage : V_{CEO}= −160V
4) Lead Free/RoHS Compliant.

●Inner circuit



●Applications

Motor driver , LED driver
Power supply

●Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1275	CPT3	6595	TL	330	16	2,500	B1275

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●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	−160	V
Collector-emitter voltage		V_{CEO}	−160	V
Emitter-base voltage		V_{EBO}	−5	V
Collector current	DC	I_C	−1.5	A
	Pulsed	I_{CP} *1	−3.0	A
Power dissipation		P_D *2	1	W
		P_D *3	10	W
Junction temperature		T_j	150	°C
Range of storage temperature		T_{stg}	−55 to +150	°C

*1 Pw=100ms , single pulse
*2 Mounted on a substrate
*3 Tc=25°C

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-emitter breakdown voltage	BV_{CEO}	I_C = −1mA	−160	-	-	V
Collector-base breakdown voltage	BV_{CBO}	I_C = −50μA	−160	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I_E = −50μA	−5	-	-	V
Collector cut-off current	I_{CBO}	V_{CB} = −120V	-	-	−1	μA
Emitter cut-off current	I_{EBO}	V_{EB} = −4V	-	-	−1	μA
Collector-emitter saturation voltage	$V_{CE(sat)}$ *4	I_C = −1A, I_B = −0.1A	-	-	−2	V
DC current gain	h_{FE}	V_{CE} = −5V, I_C = −100mA	82	-	180	-
Transition frequency	f_T	V_{CE} = −5V, I_E = 100mA f=30MHz	-	50	-	MHz
Output capacitance	C_{ob}	V_{CB} = −10V, I_E = 0A, f = 1MHz	-	30	-	pF

*4 Pulsed

●h_{FE} rank categories

Rank	P
h_{FE}	82 to 180

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●**Electrical characteristic curves**(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

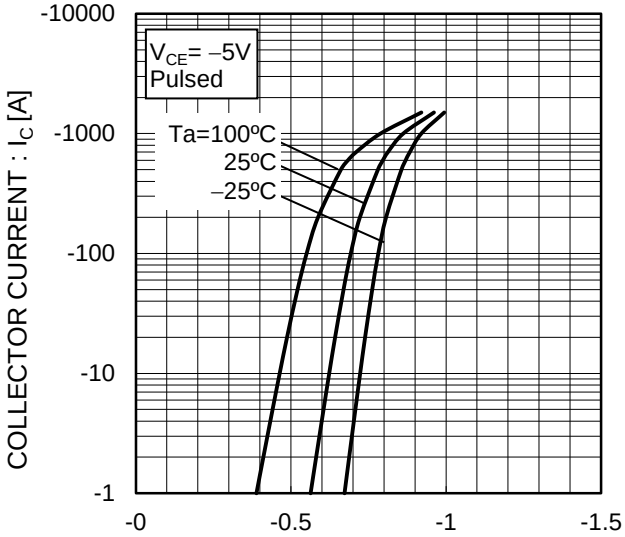


Fig.2 Typical Output Characteristics

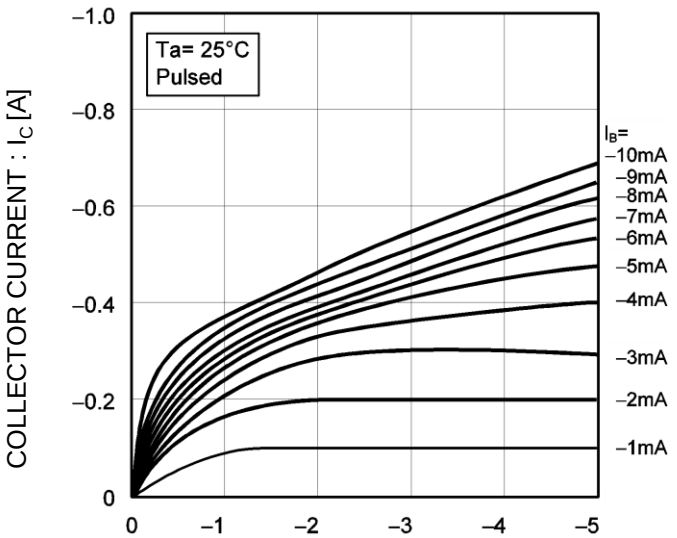


Fig.3 DC Current Gain vs. Collector Current(I)

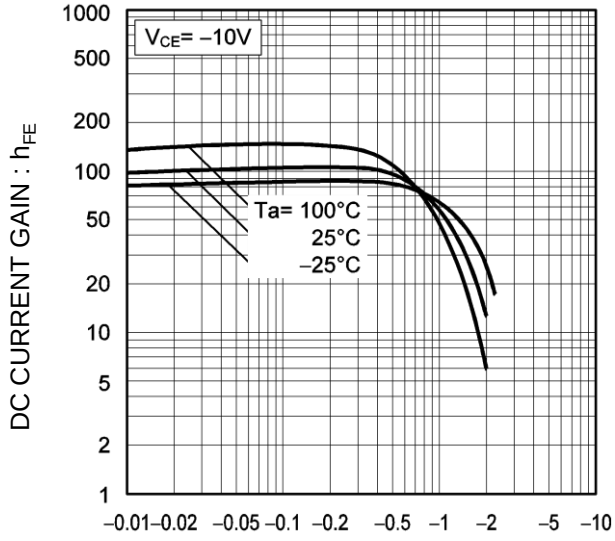
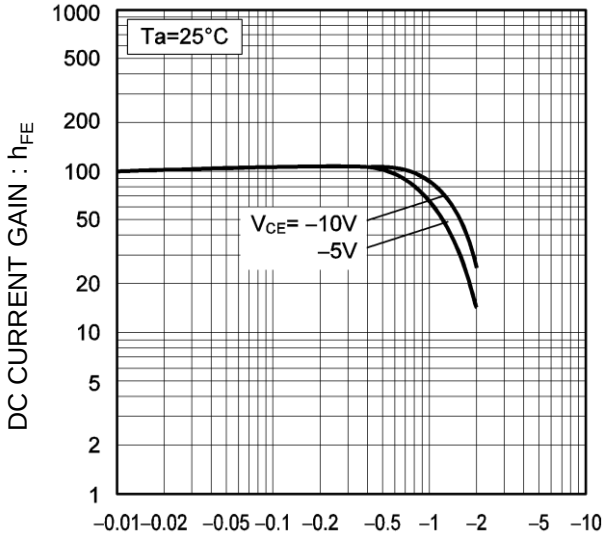


Fig.4 DC current gain vs. output current (II)



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●**Electrical characteristic curves**(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

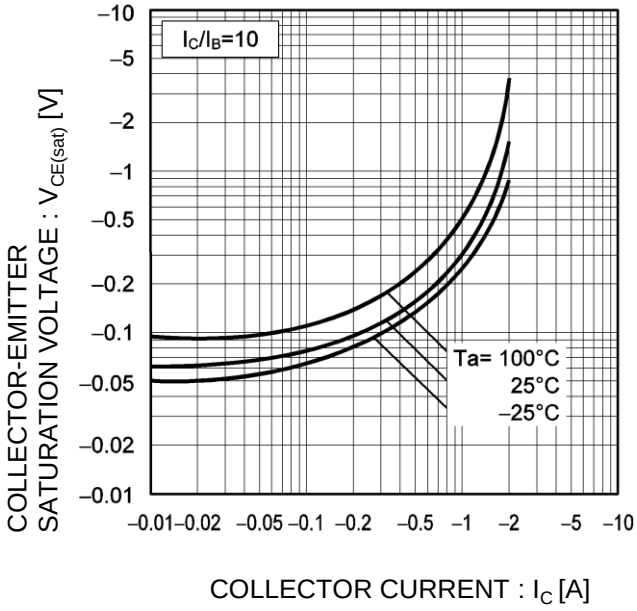


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

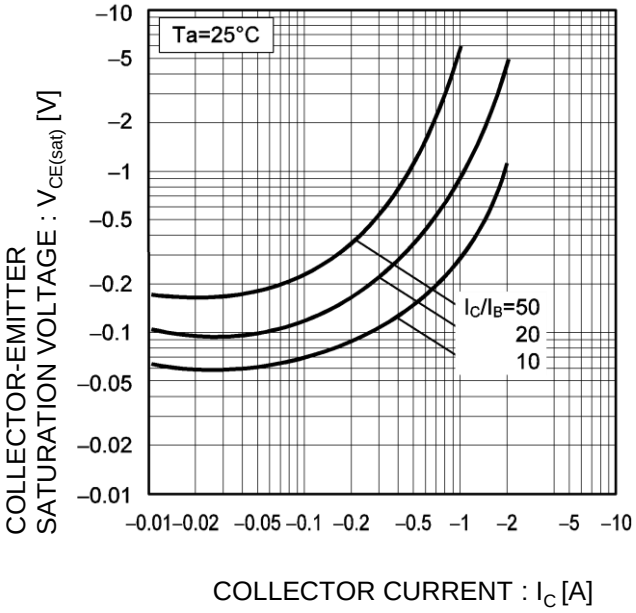


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

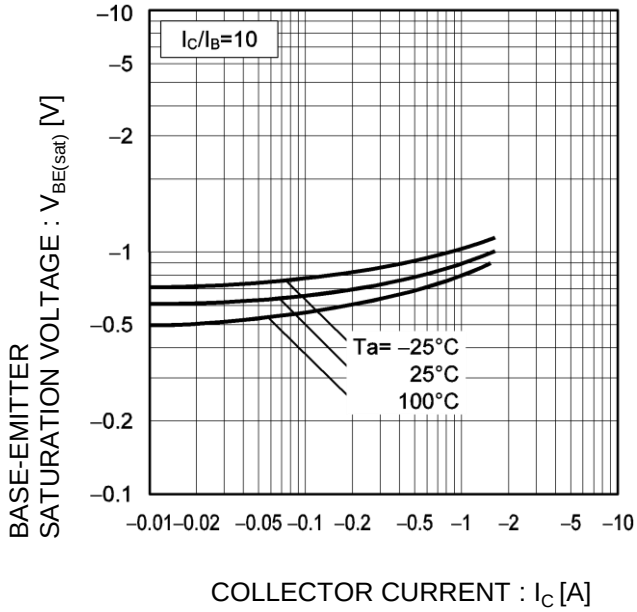
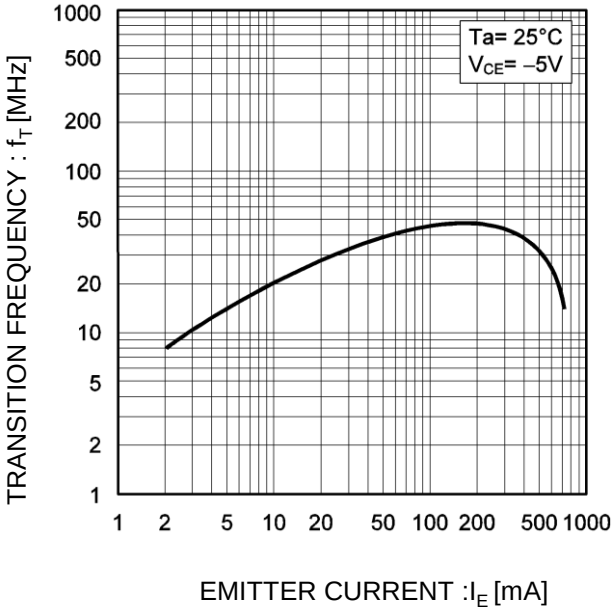


Fig.8 Gain Bandwidth Product vs. Emitter Current



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●**Electrical characteristic curves**(Ta = 25°C)

Fig.9 Collector output capacitance vs. Collector-Base Voltage

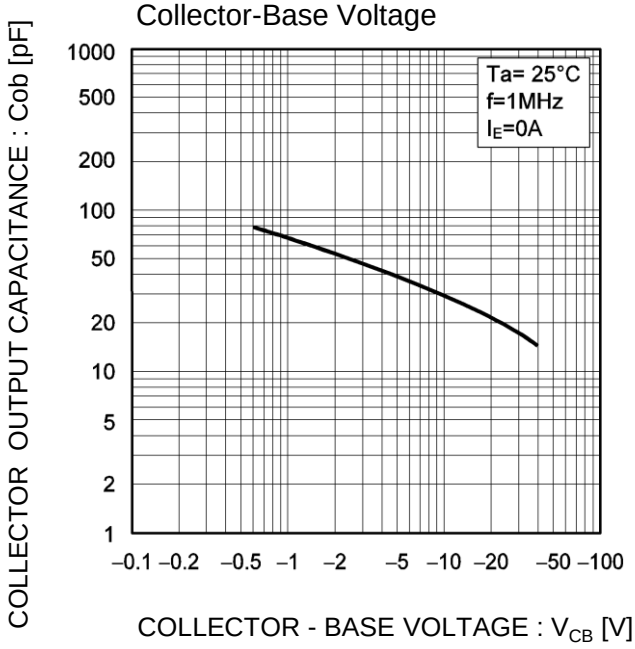
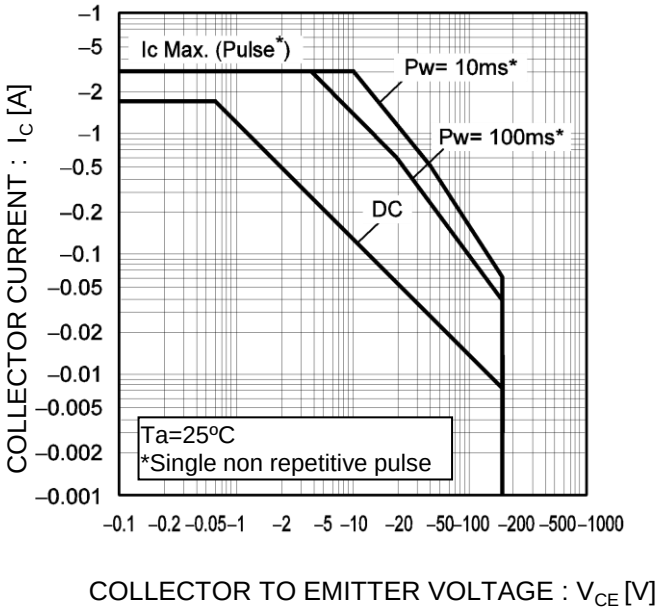


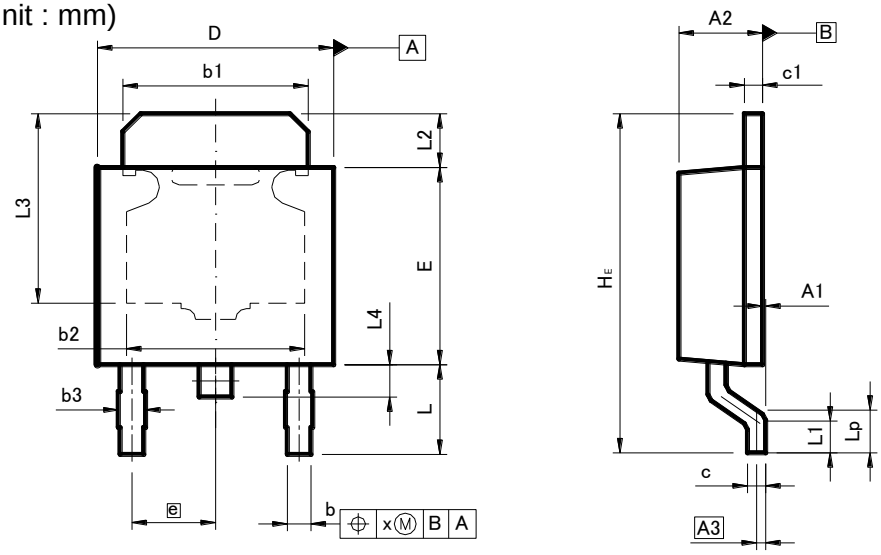
Fig.10 Safe Operating Area

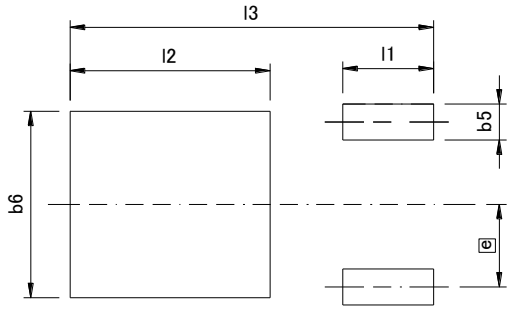


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●**Dimensions** (Unit : mm)

CPT3





Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A1	0.00	0.15	0.000	0.006
A2	2.20	2.50	0.087	0.098
A3	0.25		0.010	
b	0.55	0.75	0.022	0.030
b1	5.00	5.30	0.197	0.209
b2	5.00		0.197	
b3	0.75		0.030	
c	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
e	2.30		0.091	
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.110
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.90		0.035	
Lp	1.00	1.60	0.039	0.063
x	–	0.25	–	0.010

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b5	–	1.00	–	0.04
b6	–	5.20	–	0.205
l1	–	2.50	–	0.098
l2	–	5.50	–	0.217
l3	–	10.00	–	0.394

Dimension in mm / inches

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3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.
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